## UNITED STATES PATENT AND TRADEMARK OFFICE **CERTIFICATE OF CORRECTION**

PATENT NO.

: 7,060,599 B2

Page 1 of 1

APPLICATION NO.: 10/804578

**DATED** 

: June 13, 2006

INVENTOR(S)

: Fernando Gonzalez and Randhir Thakur

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

On the title page:

In the section (56) References Cited: OTHER PUBLICATIONS

delete second occurrence of "Shu Qin, et al., "Plasma Immersion Ion Implantation

Doping Experiments for

Microelectronics," pp. 962-968, J. Vac. Sci. Technol. B 12(2), Mar./Apr. 1994."

In the specification:

COLUMN 2, Line 42, change "modem integrated circuit" to

--modern integrated circuit--

COLUMN 6, Line 32,

after "portion" insert --28--

In the claims:

CLAIM 3, COLUMN 8, LINE 21, change "1750 Åfrom" to --1750 Å from--

Signed and Sealed this

Second Day of January, 2007

JON W. DUDAS Director of the United States Patent and Trademark Office